

Advanced IGBT/MOSFET driver

Features

- 1.7 A sink / 1.3 A source (typ) current capability
- Active Miller clamp feature
- Desaturation detection
- Adjustable turn-on delay
- UVLO protection
- 2k V ESD protection

Applications

- 1200 V 3-phase inverter
- Motor control systems
- UPS

Description

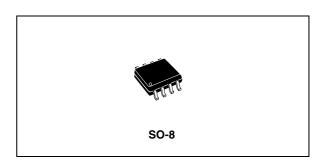
This device is an advanced gate driver for IGBTs and power MOSFETs. Control and protection functions are included and allow the design of high reliability systems.

The innovative active Miller clamp function eliminates the need for negative gate drive in most applications and allows the use of a simple bootstrap supply for the high side driver.

The TD352 includes an adjustable turn-on delay. This feature can be used to implement reliable deadtime between high and low sides of a half bridge. An external resistor and capacitor are used to provide accurate timing.



| Order codes | Temperature range Package | | Packaging |
|-------------|---------------------------|------|---------------|
| TD352ID | -40°C. +125°C | SO-8 | Tube |
| TD352IDT | | | Tape and reel |



Contents TD352

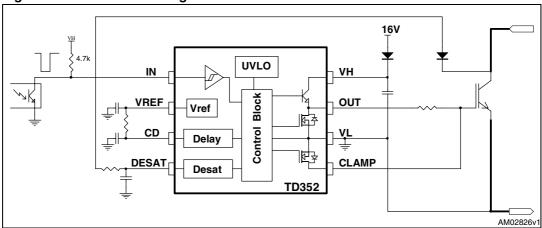
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TD352 Block diagram

1 Block diagram

Figure 1. TD352 block diagram



Pin connections TD352

2 Pin connections

Figure 2. Pin connections (top view)

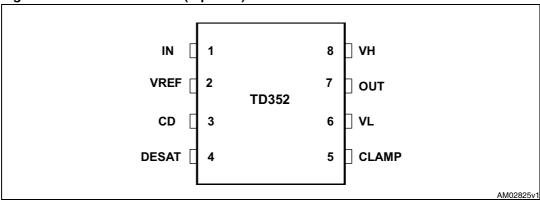


Table 2. Pin description

| Pin n° | Name | Туре | Function |
|--------|------|---------------------------------|-------------------------|
| IN | 1 | Analog input | Input |
| VREF | 2 | Analog output | +5 V reference voltage |
| CD | 3 | Timing capacitor | Turn on delay |
| DESAT | 4 | Analog input | Desaturation protection |
| CLAMP | 5 | Analog output | Miller clamp |
| VL | 6 | Power supply | Signal ground |
| OUT | 7 | Analog output Gate drive output | |
| VH | 8 | Power supply Positive supply | |

3 Absolute maximum ratings

Table 3. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|--------------------|--------------------------------------|------------------|------|
| VHL | Maximum supply voltage (VH - VL) | 28 | V |
| V _{out} | Voltage on OUT, CLAMP, DESAT pins | VL-0.3 to VH+0.3 | ٧ |
| V _{other} | Voltage on other pins (IN, CD, VREF) | -0.3 to 7 | ٧ |
| P _d | Power dissipation | 500 | mW |
| T _{stg} | Storage temperature | -55 to 150 | °C |
| Tj | Maximum junction temperature | 150 | °C |
| R _{thJA} | Thermal resistance junction-ambient | 150 | °C/W |
| ESD | Electrostatic discharge (HBM) | 2 | kV |

Table 4. Operating conditions

| Symbol | Parameter | Value | Unit |
|-------------------|--------------------------------------|------------|------|
| VH | Positive supply voltage vs. VL | UVLO to 26 | V |
| T _{oper} | Operating free air temperature range | -40 to 125 | °C |

Electrical characteristics TD352

4 Electrical characteristics

 T_A = -20 to 125 °C, VH = 16 V, unless otherwise specified.

Table 5. Electrical characteristics

| Symbol | Parameter | Test condition | Min | Тур | Max | Unit |
|---------------------|-------------------------------|--|--------|------|------------|----------|
| Input | | | | | | |
| V _{ton} | IN turn-on threshold voltage | | 0.8 | 1.0 | | V |
| V_{toff} | IN turn-off threshold voltage | | | 4.0 | 4.2 | V |
| I _{inp} | IN input current | IN input voltage < 4.5V | | | 1 | μΑ |
| Voltage refe | erence ⁽¹⁾ | <u>.</u> | | | | |
| V _{ref} | Voltage reference | T = 25°C | 4.85 | 5.00 | 5.15 | V |
| I _{ref} | Maximum output current | | 10 | | | mA |
| Clamp | | | | | | |
| V _{tclamp} | CLAMP pin voltage threshold | | | 2.0 | | V |
| V _{CL} | Clamp low voltage | I _{csink} = 500mA | | | 2.5 | V |
| Delay | | · | | | | |
| V _{tdel} | Voltage threshold | | | 2.5 | | V |
| R _{del} | Discharge resistor | I=1mA | | | 500 | Ω |
| Desaturation | on protection | · | | | | |
| V _{des} | Desaturation threshold | | | VH-2 | | V |
| I _{des} | Source current | | | 250 | | μΑ |
| Output | | • | • | | | |
| I _{sink} | Output sink current | V _{out} = 6V | 1000 | 1700 | | mA |
| I _{src} | Output source current | V _{out} = VH-6V | 750 | 1300 | | mA |
| V _{OL1} | Output low voltage 1 | I _{osink} = 20mA | | | 0.35 | V |
| V _{OL2} | Output low voltage 2 | I _{osink} = 500mA | | | 2.5 | V |
| V _{OH1} | Output high voltage 1 | I _{osource} = 20mA | VH-2.5 | | | V |
| V_{OH2} | Output high voltage 2 | I _{osource} = 500mA | VH-4.0 | | | V |
| t _r | Rise time | C _L = 1nF, 10% to 90% | | | 100 | ns |
| t _f | Fall time | C _L = 1nF, 90% to 10% | | | 100 | ns |
| t _{don} | Turn on propagation delay | 10% OUT change: $R_d = 4.7k\Omega$, no C_d $R_d = 11k\Omega$, $C_d = 220$ pF | 1.8 | 2.0 | 500 2.2 | ns µs |
| t _{doff} | Turn off propagation delay | 10% OUT change | | | 400 | ns |

Table 5. Electrical characteristics (continued)

| Symbol | Parameter | Test condition | Min | Тур | Max | Unit |
|-------------------|-----------------------|-------------------|-----|-----|-----|------|
| Under volta | ge lockout (UVLO) | | | | | |
| UVLOH | UVLO top threshold | | 10 | 11 | 12 | ٧ |
| UVLOL | UVLO bottom threshold | | 9 | 10 | 11 | ٧ |
| V _{hyst} | UVLO hysteresis | UVLOH-UVLOL | 0.5 | 1 | | ٧ |
| Supply curr | ent | | | | | |
| I _{in} | Quiescent current | OUT = 0V; no load | | | 2.5 | mA |

^{1.} Recommended capacitor range on VREF pin is 10 nF to 100 nF

5 Functional description

5.1 Input stage

The TD352 IN input is internally clamped at about 5 V to 7 V. The input is triggered by the signal edge. When using an open collector optocoupler, the resistive pull-up resistor can be connected to either VREF or VH.

Recommended pull-up resistor value with VH=16 V is from 4.7 k Ω to 22 k Ω

5.2 Voltage reference

A voltage reference is used to create accurate timing for the turn-on delay with external resistor and capacitor.

A decoupling capacitor (10 nF to 100 nF) on the VREF pin is required to ensure good noise rejection.

5.3 Active Miller clamp

The TD352 offers an alternative solution to the problem of Miller current in IGBT switching applications. Instead of driving the IGBT gate to a negative voltage to increase the safety margin, the TD352 uses a dedicated CLAMP pin to control the Miller current. When the IGBT is off, a low impedance path is established between the IGBT gate and emitter to carry the Miller current, and the voltage spike on the IGBT gate is greatly reduced.

During turn-off, the gate voltage is monitored and the clamp output is activated when the gate voltage goes below 2 V (relative to VL). The clamp voltage is VL+4V max for a Miller current up to 500 mA. The clamp is disabled when the IN input is triggered again.

The CLAMP function does not affect the turn-off characteristic, but only keeps the gate at low level throughout the off time. The main benefit is that negative voltage can be avoided in many cases, allowing a bootstrap technique for the high side driver supply.

5.4 Turn-on delay

Turn-on (T_a) delay is programmable through external resistor R_d and capacitor C_d for accurate timing. T_a is approximately given by (see *Figure 5*):

$$T_a (\mu s) = 0.7 * R_d (k\Omega) * C_d (nF)$$

The turn-on delay can be disabled by connecting the CD pin to VREF with a 4.7 k Ω resistor. Input signals with ON-time smaller than T_a are ignored.

Desaturation protection 5.5

Desaturation protection ensures the protection of the IGBT in the event of overcurrent. When the DESAT voltage goes higher than VH-2V, the TD352 OUT pin is driven low. The fault state is only exited after a power-down and power-up cycle.

A programmable blanking time is used to allow enough time for IGBT saturation. Blanking time is provided by an internal current source and external C_{des} capacitor. The T_{bdes} blanking time value is given by:

$$T_{bdes} = V_{des} * C_{des} / I_{des}$$

At VH=16V, T_{bdes} is approximately given by:

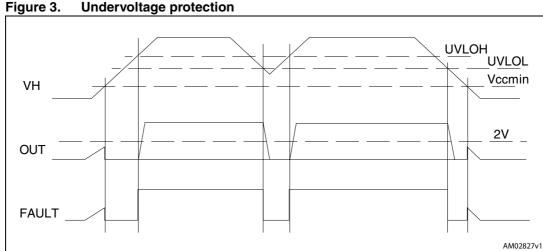
$$T_{bdes}$$
 (µs) = 0.056 * C_{des} (pF)

5.6 Output stage

The output stage is able to sink/source 1.7 A/1.3 A (typical) at 25 °C and 1.0 A/0.75 A min. over the full temperature range. This current capability is specified near the usual IGBT Miller plateau.

5.7 Undervoltage protection

Undervoltage detection protects the application in the event of a low VH supply voltage (during startup or a fault situation). During undervoltage, the OUT pin is driven low (active pull-down for VH>2V, and passive pull-down for VH<2V).



UVLO IN VRE<u>F</u> 5V Vref Control Block CLAMP DESAT VH OUT 垴 VL AM02828v1

Figure 4. Detailed internal schematic

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TD352 Timing diagrams

6 Timing diagrams

Figure 5. General turn-on and turn-off sequence

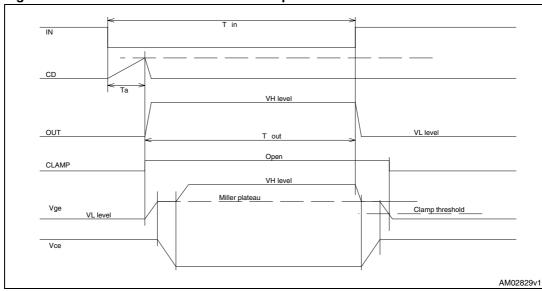
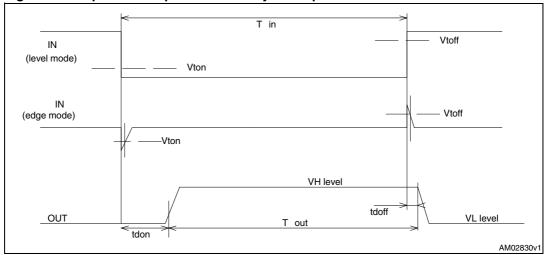


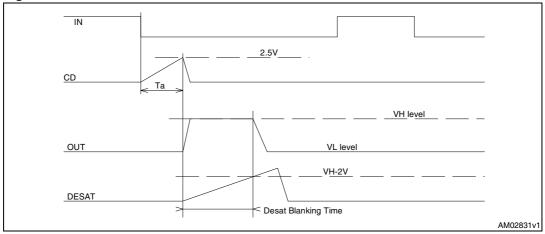
Figure 6. Input and output waveform dynamic parameters



Timing diagrams TD352

Figure 7. Desaturation fault

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7 Typical performance curves

Figure 8. Quiescent current vs temperature Figure 9. Rdel resistance vs temperature

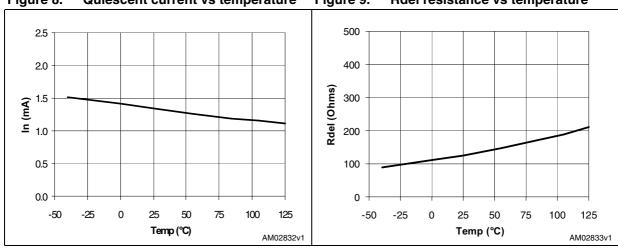
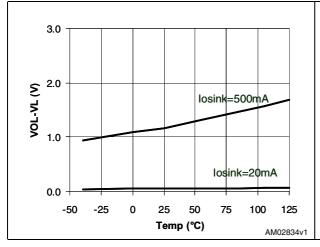
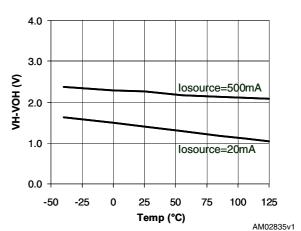


Figure 10. Low level output voltage vs temp. Figure 11. High level output voltage vs temp.

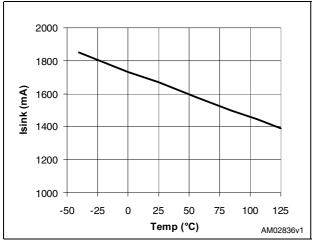


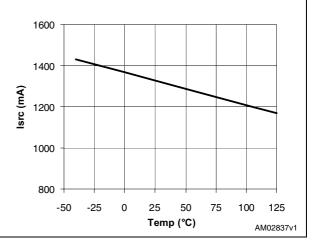


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Figure 12. Sink current vs temperature

Figure 13. Source current vs temperature





8 Application diagrams

Figure 14. Single supply IGBT drive with active Miller clamp and DESAT protection

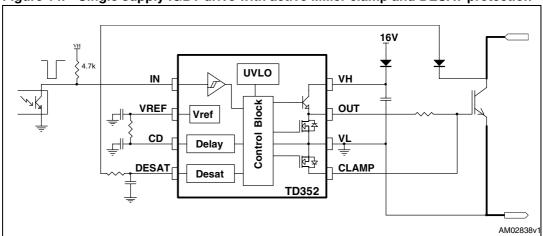


Figure 15. Use of DESAT input for direct overcurrent detection

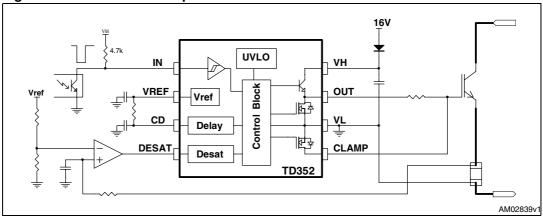
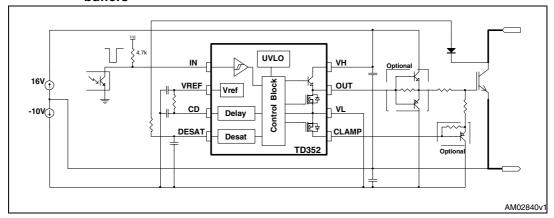


Figure 16. Large IGBT drive with negative voltage gate drive and optional current buffers



Package mechanical data 9

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Table 6. SO-8 mechanical data

| Dim. | | mm. | | | inch | | |
|------|------|------|------|-------|-------|-------|--|
| Dim. | Min. | Тур | Max. | Min. | Тур. | Max. | |
| Α | 1.35 | | 1.75 | 0.053 | | 0.069 | |
| A1 | 0.10 | | 0.25 | 0.04 | | 0.010 | |
| A2 | 1.10 | | 1.65 | 0.043 | | 0.065 | |
| В | 0.33 | | 0.51 | 0.013 | | 0.020 | |
| С | 0.19 | | 0.25 | 0.007 | | 0.010 | |
| D | 4.80 | | 5.00 | 0.189 | | 0.197 | |
| E | 3.80 | | 4.00 | 0.150 | | 0.157 | |
| е | | 1.27 | | | 0.050 | | |
| Н | 5.80 | | 6.20 | 0.228 | | 0.244 | |
| h | 0.25 | | 0.50 | 0.010 | | 0.020 | |
| L | 0.40 | | 1.27 | 0.016 | | 0.050 | |
| k | | • | (ma | x.) 8 | • | | |
| ddd | | | 0.1 | | | 0.04 | |

Figure 17. SO-8 mechanical drawing △ ddd C С 0016023/C

TD352 Revision history

10 Revision history

Table 7. Document revision history

| Date | Revision | Changes | | |
|---------------|-------------------|--|--|--|
| 01-Nov-2004 | 1 Initial release | | | |
| 13-Jun-2011 2 | | Deleted order code TD352IN. Content reworked to improve readability. | | |

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